

Supporting Information

Defect healing via a gradient cooling strategy for efficient all-inorganic perovskite solar cells

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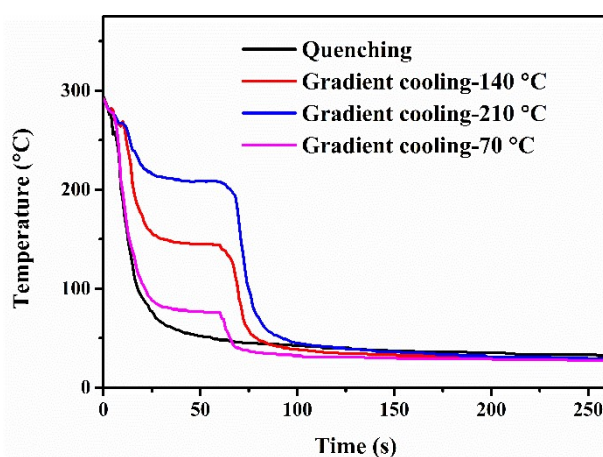


Figure S1. Cooling curves of quenching and gradient cooling processes.

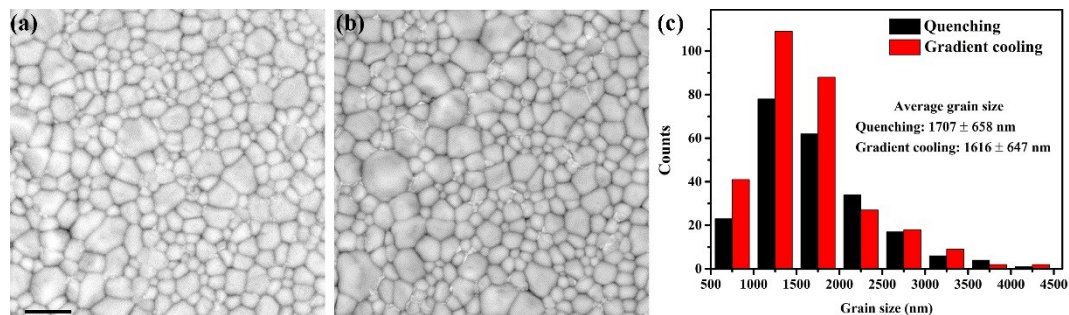


Figure S2. Top view SEM images of the quenching film (a) and gradient cooling film (b). The scale bar is 2 μm . (c) Grain size distribution histograms of perovskite films prepared by different cooling processes.

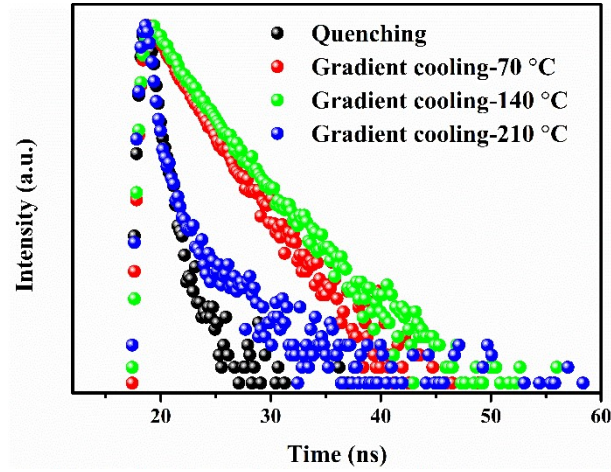


Figure S3. PL decay curves of perovskite films obtained from different cooling processes. The substrate was glass.

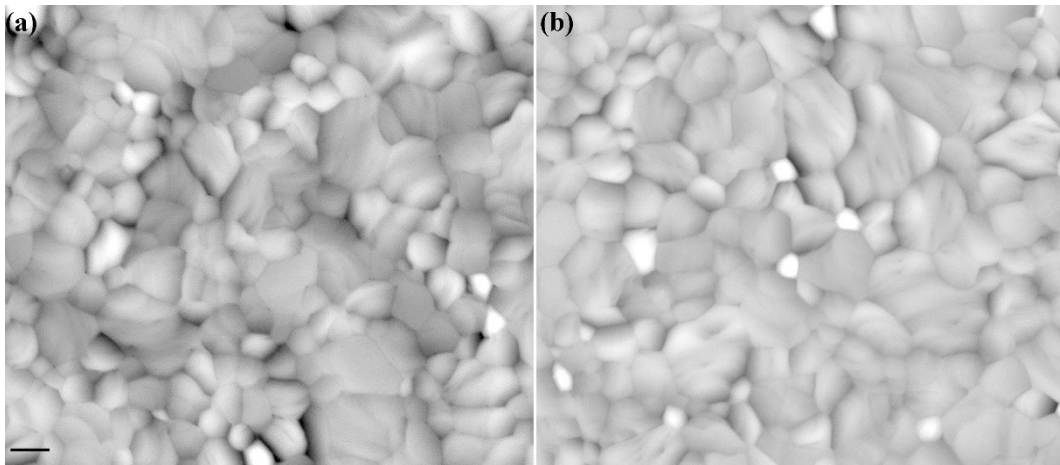


Figure S4. Top-view SEM images of perovskite films on the glass substrates. (a) The quenching film. (b) The gradient cooling film. The scale bar is 2 μm .

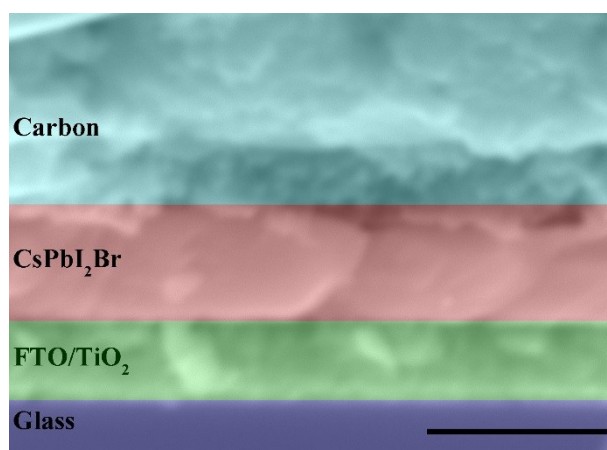


Figure S5. Cross-sectional SEM image of the device. The scale bar is 1 μm .

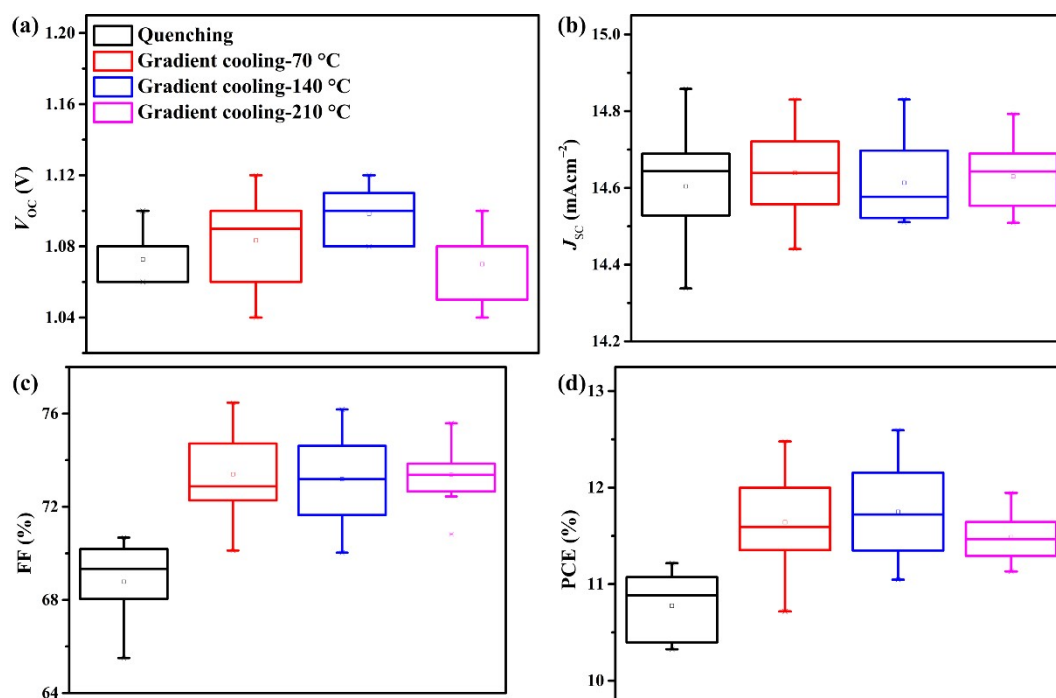


Figure S6. Box charts of photovoltaic parameters obtained from devices under different cooling conditions. (a) V_{oc} ; (b) J_{sc} ; (c) FF; (d) PCE.

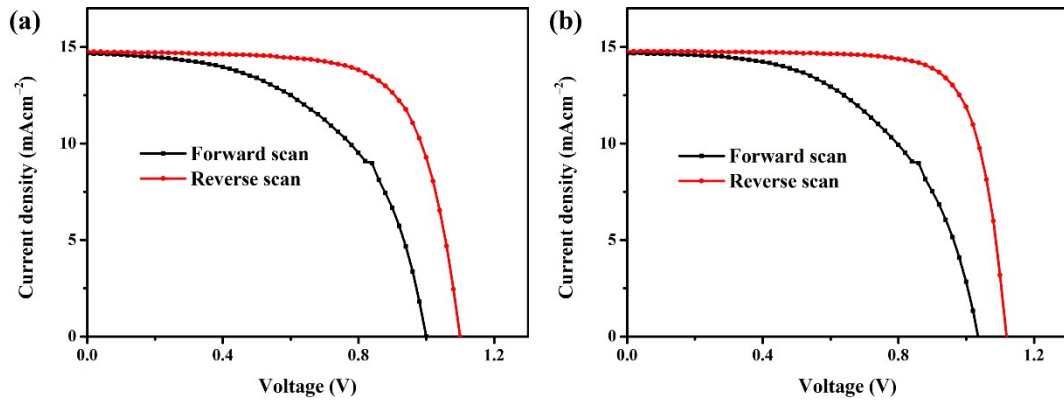


Figure S7. J - V curves under forward and reverse scanning for champion devices using quenching process (a) and gradient cooling process (b).

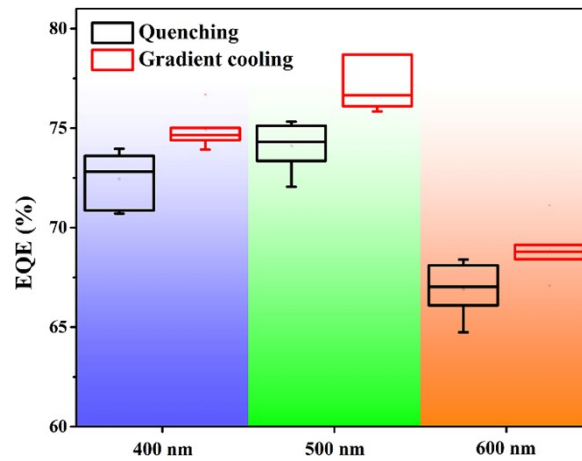


Figure S8. Statistical distribution of EQE values at three typical wavelengths (400 nm, 500 nm, and 600 nm).

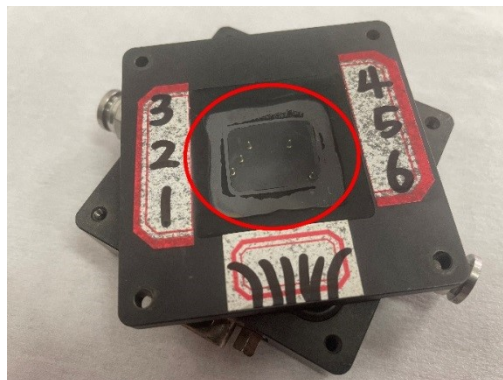


Figure S9. Optical photograph of test fixture for EQE measurement. The part in the red circle is the capping glass.

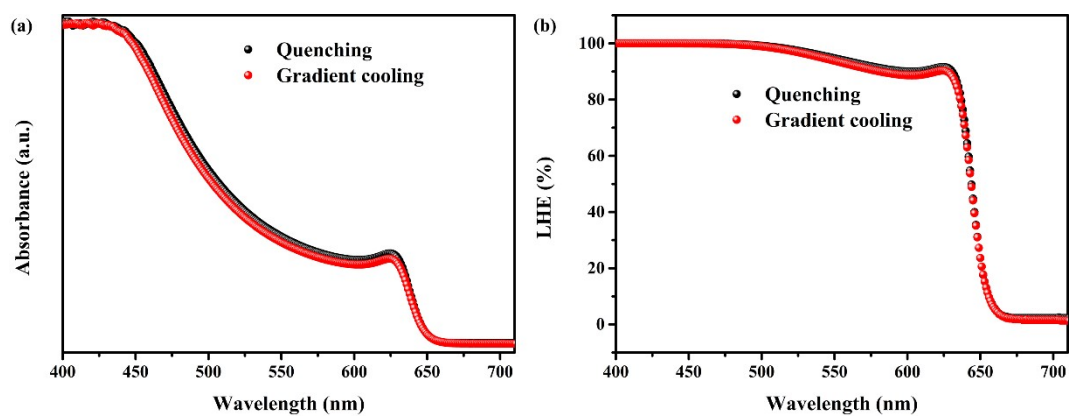


Figure S10. Absorption spectra (a) and corresponding LHE spectra (b) of perovskite films.

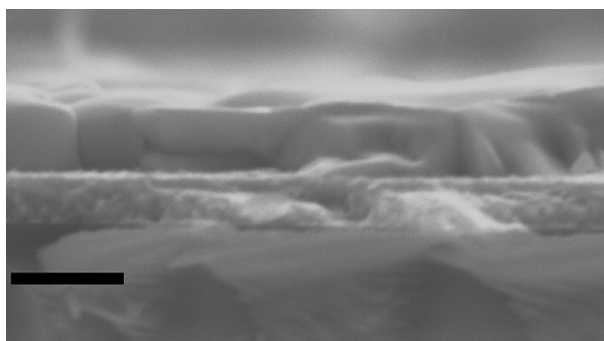


Figure S11. Cross-sectional SEM image of thick perovskite film. The scale bar is 1 μm .

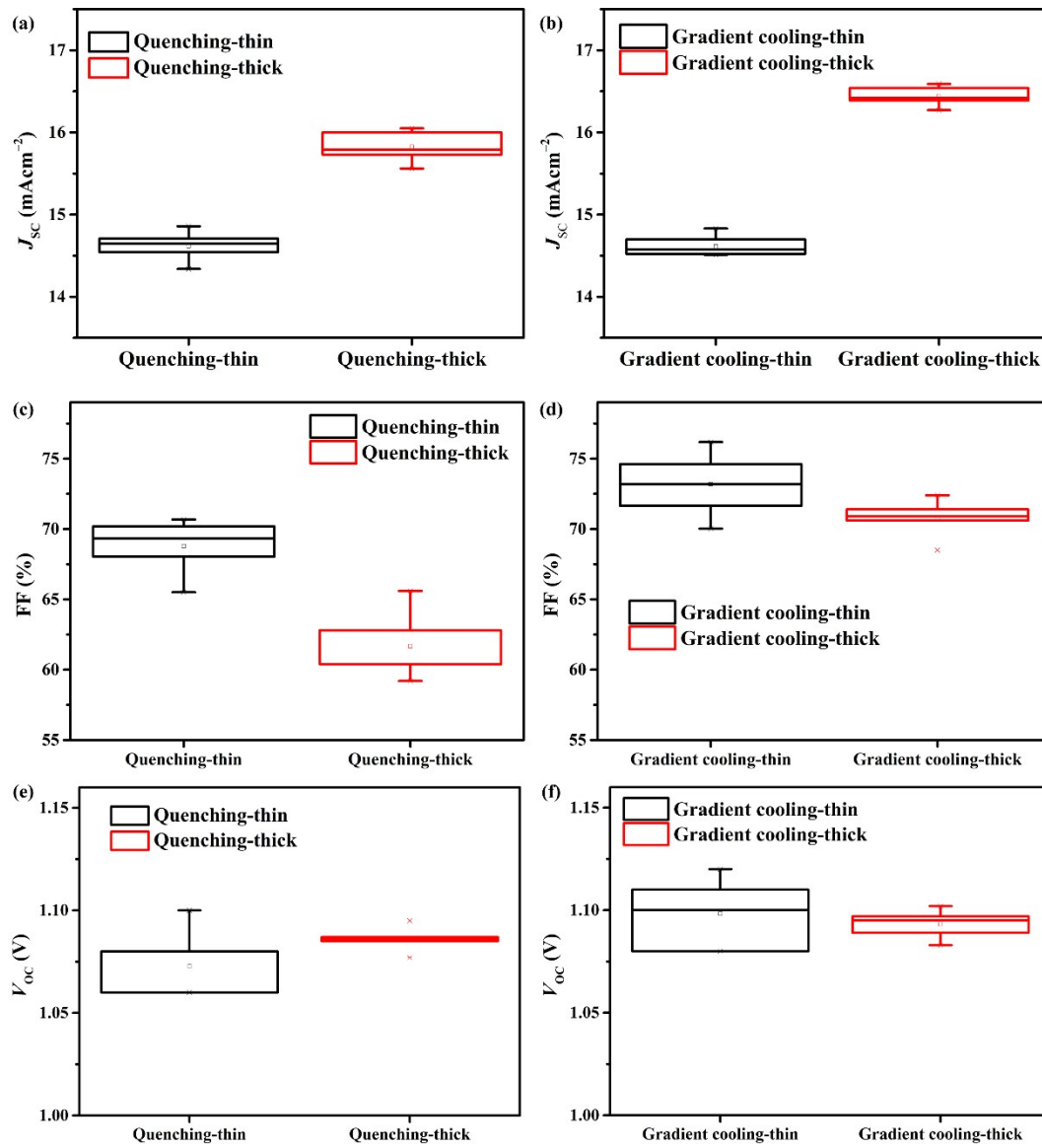


Figure S12. Comparison of photovoltaic parameters between thin and thick perovskite films. (a, b) J_{sc} ; (c, d) FF; (e, f) V_{oc} .

Table S1. TRPL fitting parameters of CsPbI₂Br films fabricated on different substrates.

Samples	Substrates	A_1 [%]	τ_1 [ns]	A_2 [%]	τ_2 [ns]	τ_{ave} [ns]
Quenching	glass	90.9	0.50	9.1	1.55	0.75
	FTO/TiO ₂	64.4	5.93	35.6	13.61	10.23
Gradient cooling-140 °C	glass	80.7	2.80	19.3	5.78	3.78
	FTO/TiO ₂	89.9	0.30	10.1	1.59	0.79
Gradient cooling-210 °C	glass	95.5	0.48	4.5	3.48	1.25
Gradient cooling-70 °C	glass	80.6	2.38	19.4	4.82	3.18

Table S2. Photovoltaic parameters of devices obtained from different cooling processes.

Devices		J_{sc} [mAcm ⁻²]	V_{oc} [V]	FF [%]	PCE [%]
Quenching	average	14.62±0.15	1.07±0.02	68.91±1.67	10.83±0.38
	best	14.77	1.10	70.30	11.42
Gradient cooling-70 °C	average	14.64±0.12	1.08±0.02	73.39±1.83	11.64±0.46
	best	14.64	1.12	76.11	12.48
Gradient cooling-140 °C	average	14.61±0.11	1.10±0.02	73.19±1.92	11.75±0.47
	best	14.76	1.12	76.18	12.59
Gradient cooling-210 °C	average	14.63±0.09	1.07±0.02	73.39±1.30	11.49±0.27
	best	14.69	1.10	73.93	11.95

Table S3. EIS fitting parameters.

Devices	R_S [Ω]	R_{CT} [Ω]	R_{rec} [Ω]	$CPE-T_1$ [F]	$CPE-T_2$ [F]
Quenching	29.89	413	1188	1.38×10^{-8}	1.12×10^{-9}
Gradient cooling	26.42	310.7	9696	3.54×10^{-8}	4.03×10^{-9}

Table S4. Photovoltaic parameters of thick devices.

Devices		J_{SC} [mAcm ⁻²]	V_{OC} [V]	FF [%]	PCE [%]
Quenching	average	15.83±0.20	1.09±0.01	61.68±2.55	10.60±0.56
	best	16.00	1.10	65.60	11.49
Gradient cooling	average	16.44±0.13	1.09±0.01	70.76±1.44	12.72±0.34
	best	16.59	1.09	72.40	13.07

Table S5. Summary of PCEs for CsPbI₂Br based C-PSCs.

Device structure	PCE [%]	Ref.
FTO/c-TiO ₂ /CsPbI ₂ Br (MABr top-seeded)/C	14.84	[1]
ITO/TiO ₂ /CsPbI ₂ Br/ATHPBr/C	14.50	[2]
FTO/c-TiO ₂ /m-TiO ₂ /CsPbI ₂ Br-CdSe QD/C	14.49	[3]
FTO/ TiCl ₄ -TiCl ₃ modified c-TiO ₂ /CsPbI ₂ Br/C	14.46	[4]
FTO/TiO ₂ /CsPbI ₂ Br/ HTAB/C	14.30	[5]
ITO/SnO ₂ /SnCl ₂ / CsPbI ₂ Br/ BMIMBF ₄ /C	14.03	[6]
ITO/SnO ₂ /SnCl ₂ / CsPbI ₂ Br/ delta-2:2-bis (1,3-dithiazole) /C	13.78	[7]
ITO/SnO ₂ /SnCl ₂ / CsPbI ₂ Br/ Cs ₂ PtI ₆ /C	13.69	[8]
FTO/SnO ₂ /CsPbI ₂ Br-PANI/C	13.52	[9]

FTO/SnO ₂ / CsPbI ₂ Br /PEAI/C	13.38	[10]
FTO/TiO ₂ / CsPbI ₂ Br (water-based spray-assisted growth)/C	13.30	[11]
FTO/TiO ₂ /CsPbI ₂ Br/CuPc/C	13.16	[12]
FTO/c-TiO ₂ /m-TiO ₂ /CsPbI ₂ Br/Carbon black/C	13.13	[13]
FTO/c-TiO ₂ /CsPbI ₂ Br-Mg(Ac) ₂ /C	13.08	[14]
FTO/c-TiO ₂ /CsPbI ₂ Br (gradient cooling)/C	13.07	This work
FTO/TiO ₂ /CsPbI ₂ Br-excess PbI ₂ /C	12.78	[15]
FTO/SnO ₂ / CsPbI ₂ Br-excess PbI ₂ /C	12.19	[16]

References (Supporting Information)

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